NCE N-Channel Super Trench Power MOSFET

Description

The NCEP0112AS uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

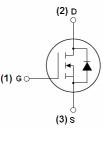
General Features

- V_{DS} =100V, I_D =12A $R_{DS(ON)}$ =9.9m Ω (typical) @ V_{GS} =10V $R_{DS(ON)}$ =11.5m Ω (typical) @ V_{GS} =4.5V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 150 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

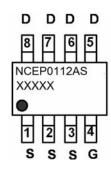
Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

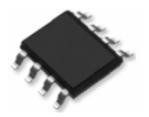
100% UIS TESTED!



Schematic diagram



Marking and pin assignment



SOP-8 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP0112AS	NCEP0112AS	SOP-8	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_A=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	12	Α
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	8	Α
Pulsed Drain Current	I _{DM}	48	Α
Maximum Power Dissipation	P _D	3.5	W
Derating factor		0.028	W/°C
Single pulse avalanche energy (Note 5)	E _{AS}	152	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 150	$^{\circ}$



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NCEP0112AS

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	36	°C/W
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Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	100	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.7	2.2	V
D : 0	-	V _{GS} =10V, I _D =12A	-	9.9	13	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =12A	-	11.5	15	mΩ
Forward Transconductance	g FS	V _{DS} =10V,I _D =12A	-	30	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	\/ -50\/\/ -0\/	-	3050	-	PF
Output Capacitance	Coss	V_{DS} =50V, V_{GS} =0V, F=1.0MHz	-	274	-	PF
Reverse Transfer Capacitance	C _{rss}	r=1.0lvin2	-	17.8	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	11	-	nS
Turn-on Rise Time	t _r	V_{DD} =50 V , I_D =12 A	-	7	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =1.6 Ω	-	30	-	nS
Turn-Off Fall Time	t _f		-	4	-	nS
Total Gate Charge	Qg	V -50V/1 -40A	-	45	-	nC
Gate-Source Charge	Q_{gs}	V_{DS} =50V, I_{D} =12A, V_{GS} =10V	-	11.6	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	6	-	nC
Drain-Source Diode Characteristics			•			•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =12A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	12	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = I_S$	-	78	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	149	-	nC

Notes:

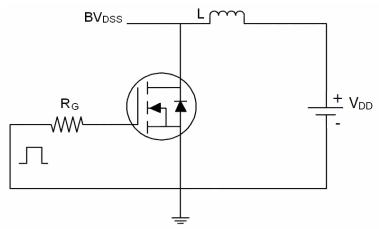
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\text{C}$,V_DD=50V,V_G=10V,L=0.5mH,Rg=25 Ω



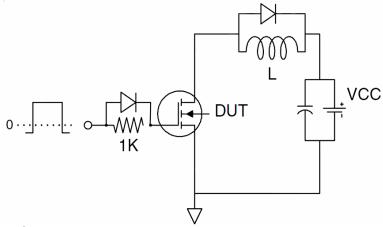
NCEP0112AS

Test Circuit

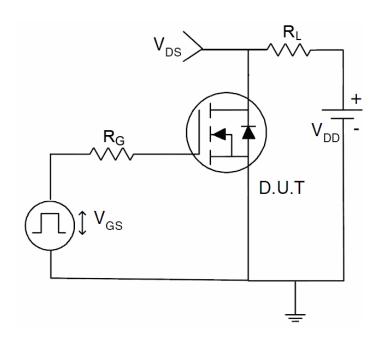
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit



Pb Free Product



Typical Electrical and Thermal Characteristics

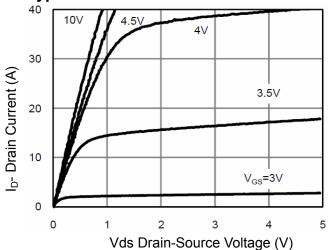


Figure 1 Output Characteristics

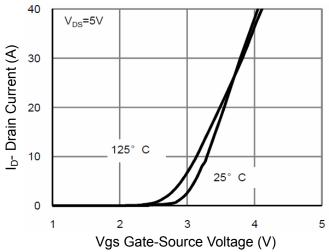


Figure 2 Transfer Characteristics

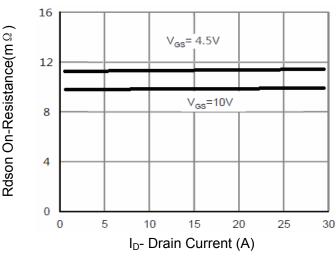


Figure 3 Rdson- Drain Current

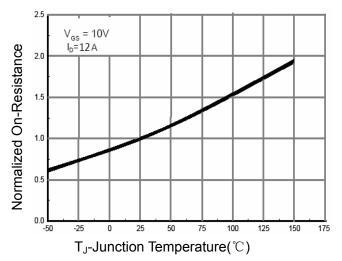


Figure 4 Rdson-Junction Temperature

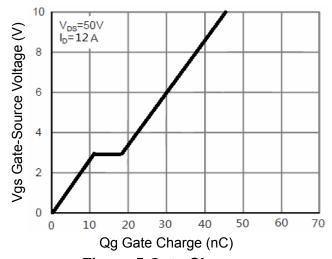


Figure 5 Gate Charge

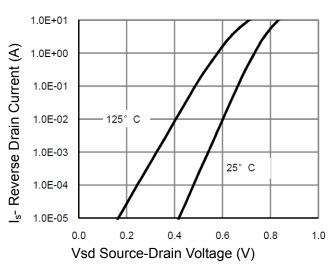
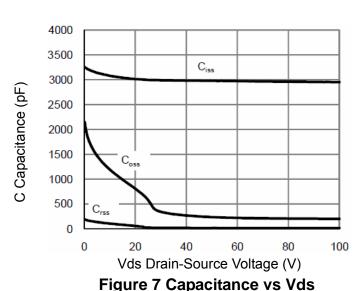
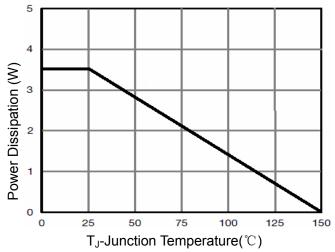


Figure 6 Source- Drain Diode Forward







100.0

10.0

R_{DS(ON)} 10μs
11μ1 100μs
11μ1 100μs
11μ1 100μs
11μ1 100μs
11μ1 10μs
11μσ 10μs
11μ

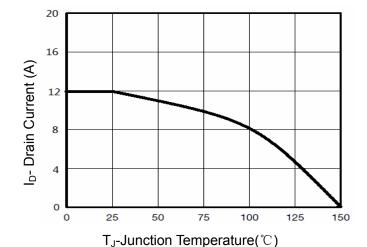
Ip- Drain Current (A)

0.0

0.01

0.1

Figure 9 Power De-rating



Vds Drain-Source Voltage (V)
Figure 8 Safe Operation Area

10

100

1000

Figure 10 Current De-rating

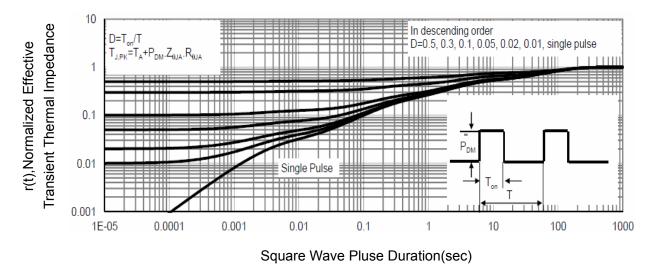
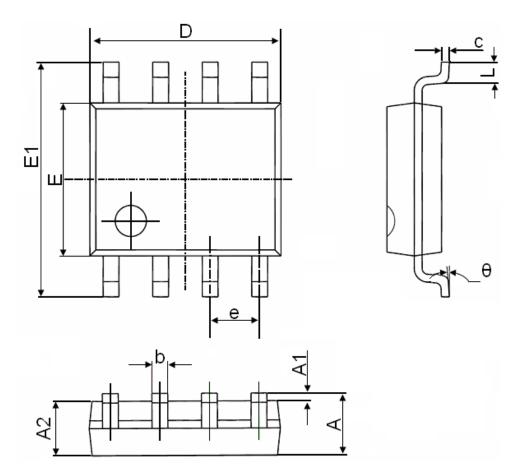


Figure 11 Normalized Maximum Transient Thermal Impedance

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SOP-8 Package Information



Cumbal	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
Α	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
С	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
Е	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
е	1.270(BSC)		0.050	(BSC)
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



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